

***New insights into the origin of visible light photocatalytic activity of nitrogen doped and oxygen deficient anatase TiO<sub>2</sub>***

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# ***Introduction***

- ❖ **TiO<sub>2</sub> is a non-toxic, relatively inexpensive and very promising photocatalyst for environmental applications.**
- ❖ **The bandgap of TiO<sub>2</sub> is large (3.0-3.2 eV) — its photocatalytic efficiency under visible light is very low.**
- ❖ **Many attempts have been made to improve its performance in visible light region:**
  - **Transition metal doping**
  - **Surface modifications.**
  - **Non-metallic elements doping**



# ***Nitrogen doping in anatase $TiO_2$***

**Two mechanisms were proposed to account for visible light activity of N-doped  $TiO_2$ :**

- **Oxygen vacancies introduced in  $TiO_2$  when prepare samples. Nitrogen atoms just act as a blocker for electron and hole recombination.**
- **Nitrogen atoms doped into substitutional sites in  $TiO_2$ .**

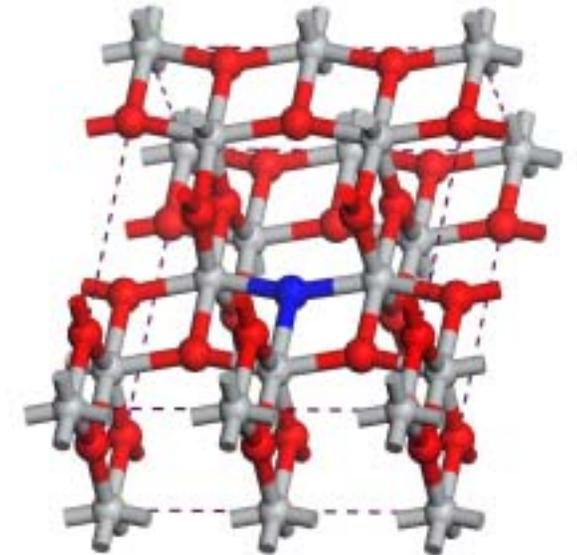
**The experimental preparation methods can introduce both doped nitrogen and oxygen vacancies → need theoretical approach.**



# Calculation methods

Modelling:  $\text{TiO}_{2-x}\text{N}_x$  or  $\text{TiO}_{2-x}$ : replace or remove O in Supercell — 24, 48, and 96 atoms  $\rightarrow$   $x=0.125, 0.062, \text{ and } 0.031$

- ❖ **CASTEP**
- **Spin-polarized GGA**
- **Ultrasoft pseudopotential**
- **Energy cutoff of Plane-wave: 500 eV**
- **PBE XC functional**



Geometry optimization  $\rightarrow$  electronic band structures  
 $\rightarrow$  Optical absorption properties

The imaginary part of the dielectric constant:

$$\varepsilon_2(\hbar\omega) = \frac{2e^2\pi}{\Omega\varepsilon_0} \sum_{k,v,c} \left| \langle \psi_k^c | \hat{u} \cdot r | \psi_k^v \rangle \right|^2 \delta(E_k^c - E_k^v - \hbar\omega) \quad (\text{Scissors operator})$$



# Stoichiometric TiO<sub>2</sub>

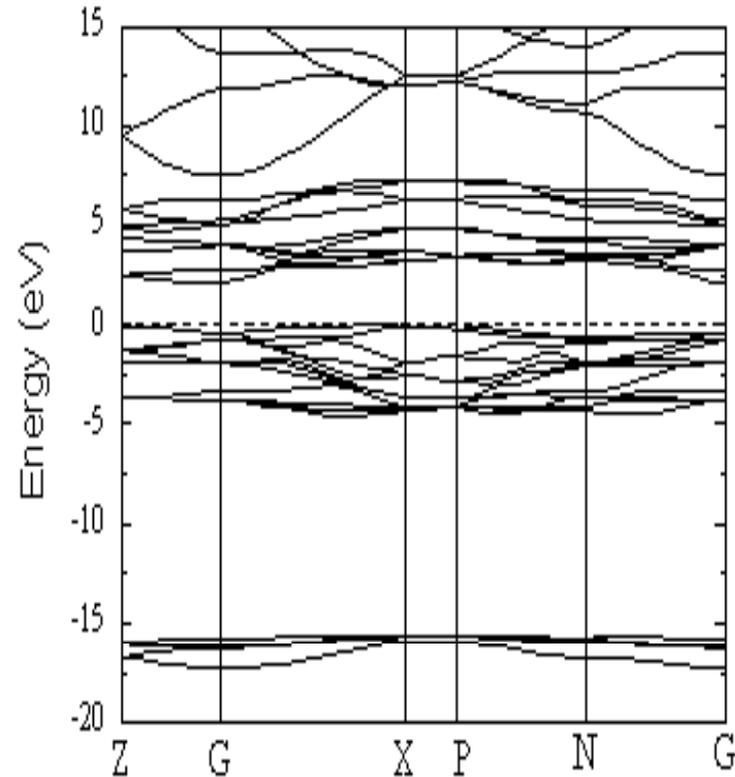
## ❖ Optimized geometry:

	This work	Experimental <sup>a</sup>
$a$ (Å)	3.7845	3.782
$c$ (Å)	9.7153	9.502
$u^b$	0.2059	0.208

<sup>a</sup>J. K. Burdett, *JACS*, Vol. 109, 3639

<sup>b</sup> $u = d_{ap}/c$ ,  $d_{ap}$  is the apical Ti-O bond length.

Mulliken analysis: Ti:+1.33 O:-0.66

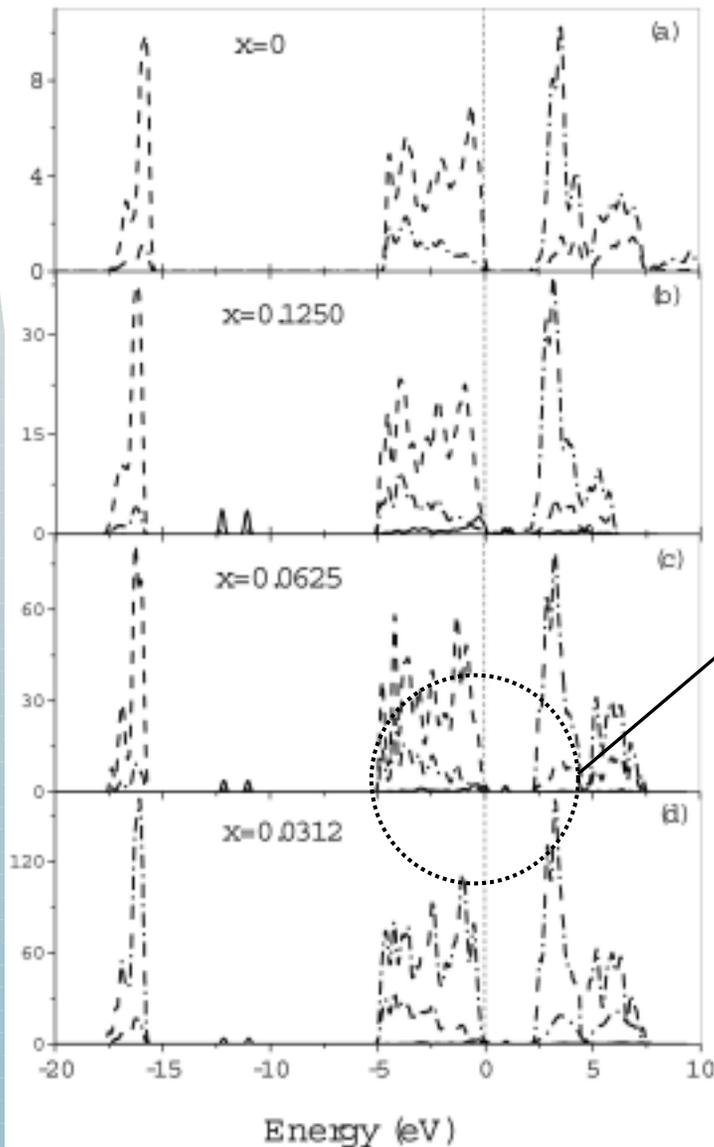


Electronic band structure along high symmetry directions in stoichiometric TiO<sub>2</sub> crystal (indirect gap 2.14 eV).

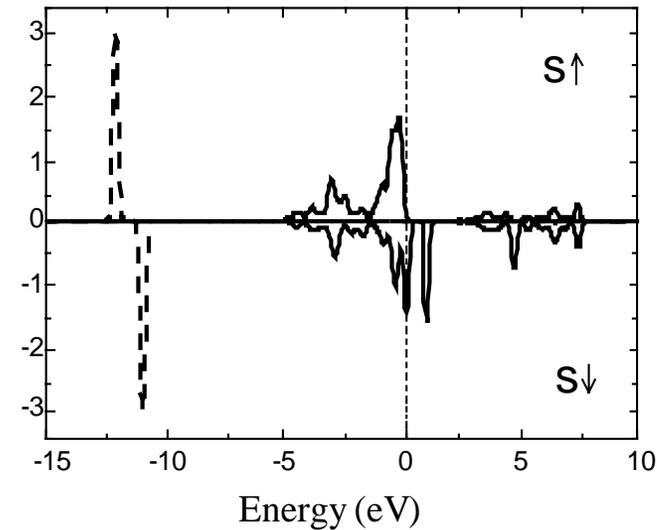


# Nitrogen doped anatase $\text{TiO}_2$

Mulliken analysis: N -0.58 -->  
N acts as a deep electron trap.



Partial density of states plots calculated for different levels of the N doping in  $\text{TiO}_2$  crystal.



PDOS for spin-up ( $s\uparrow$ ) and spin-down ( $s\downarrow$ ) electrons in nitrogen atom ( $x=0.062$ ).

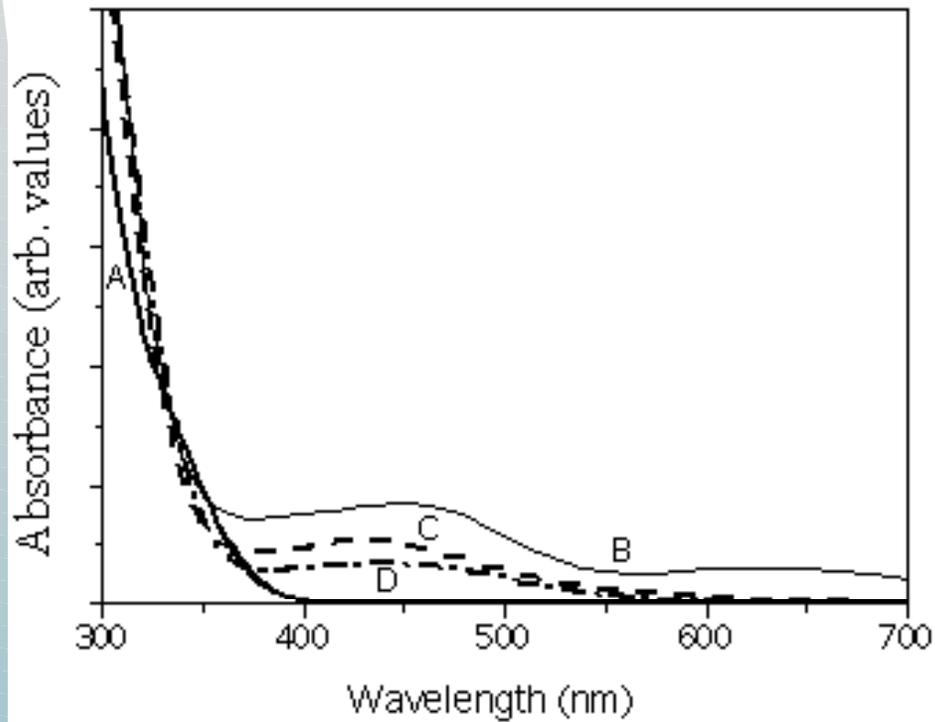
In high concentration ( $>20\%$ ), the N 2p states mix with the O 2p states the transfer of photoexcited carriers to reactive sites at the catalyst surface within their lifetime.

High doping might cause some problems :

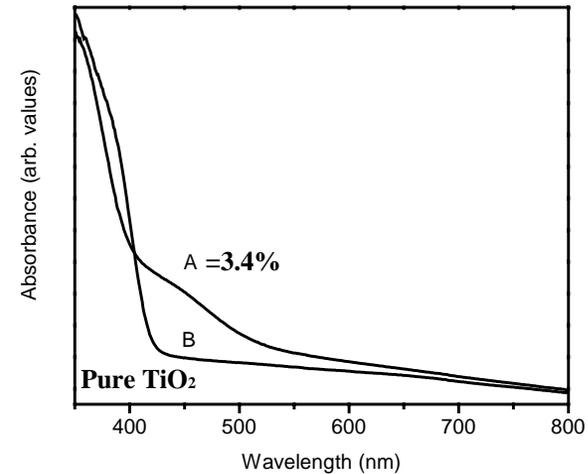
- Form  $\text{TiN}$ ;
- Introduce significant number of defects.



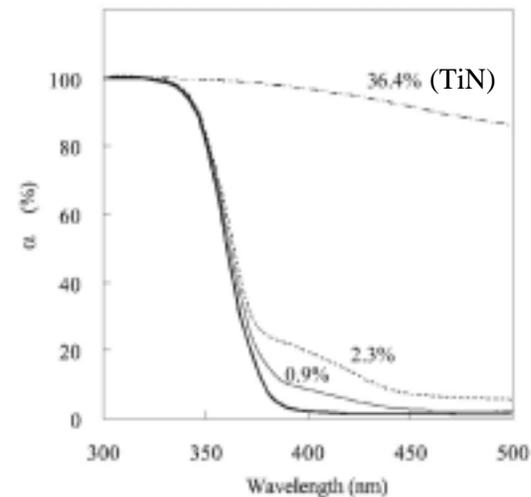
# Optical absorption spectra of N-doped TiO<sub>2</sub> in visible light region



The optical absorption spectra calculated for various N concentrations in polycrystalline TiO<sub>2</sub>. (A) undoped TiO<sub>2</sub>, (B) 12.5% nitrogen doped, (C) 6.2% nitrogen doped, (D) 3.1% nitrogen doped.



Made by Chemistry department of Cambridge



M. Miyauchi, *PCCP*, Vol. 6, 865



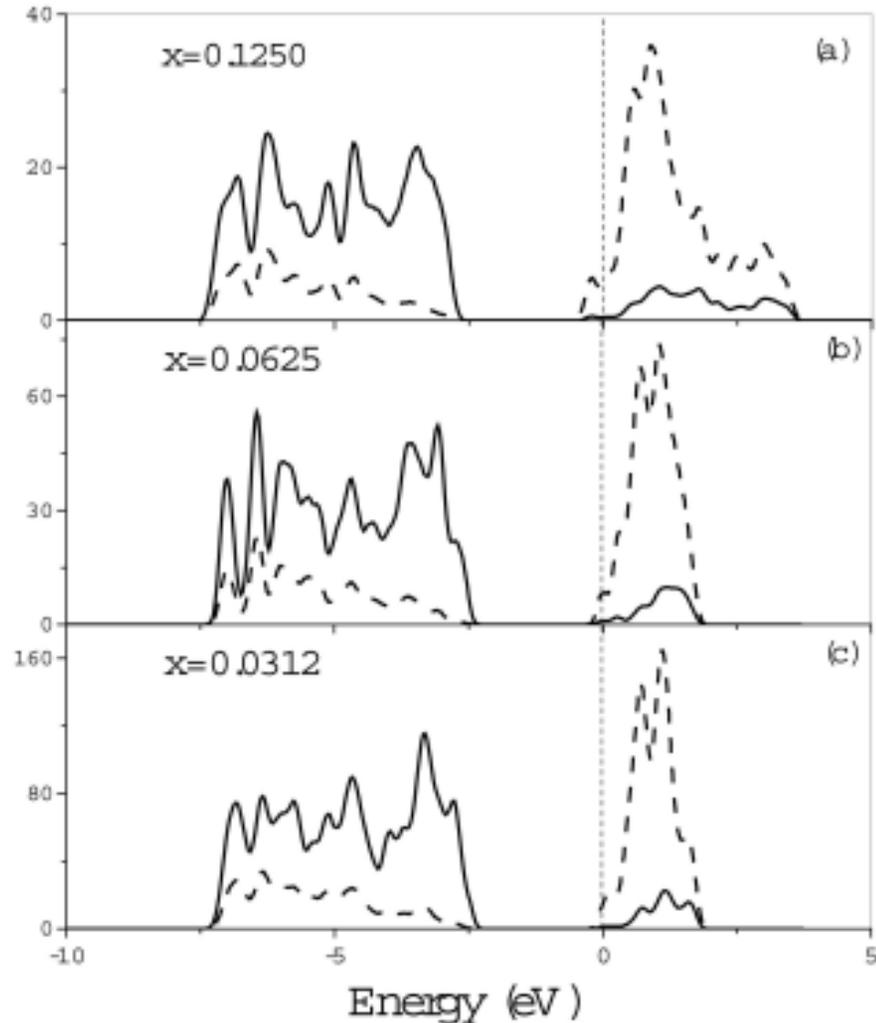
# Oxygen deficient $\text{TiO}_2$

Mulliken analysis: excess electrons were redistributed by the nearest neighbour Ti atoms around the oxygen vacancy site.

The donor states:

Calculated: 0.15 ~ 0.30 eV below the conduction band edge.

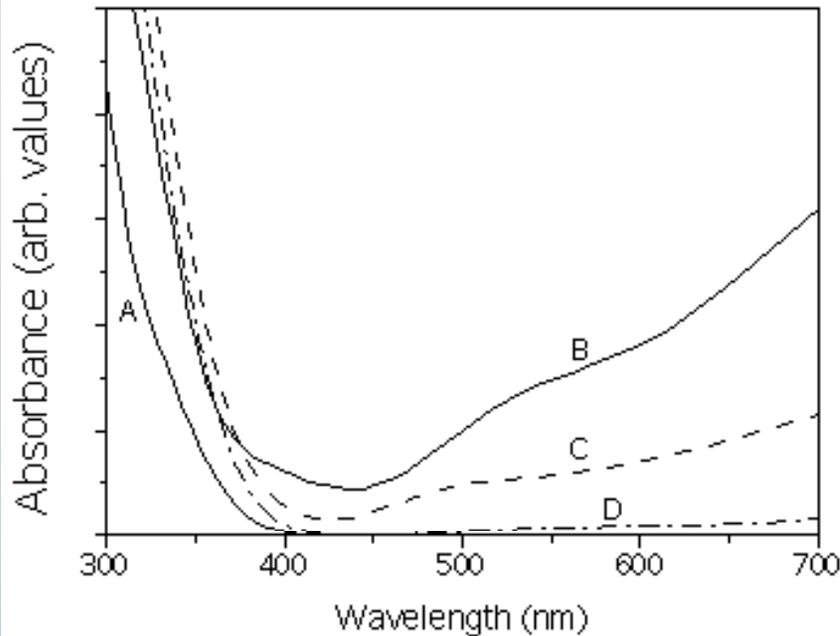
Experimental: 0.75 eV below.



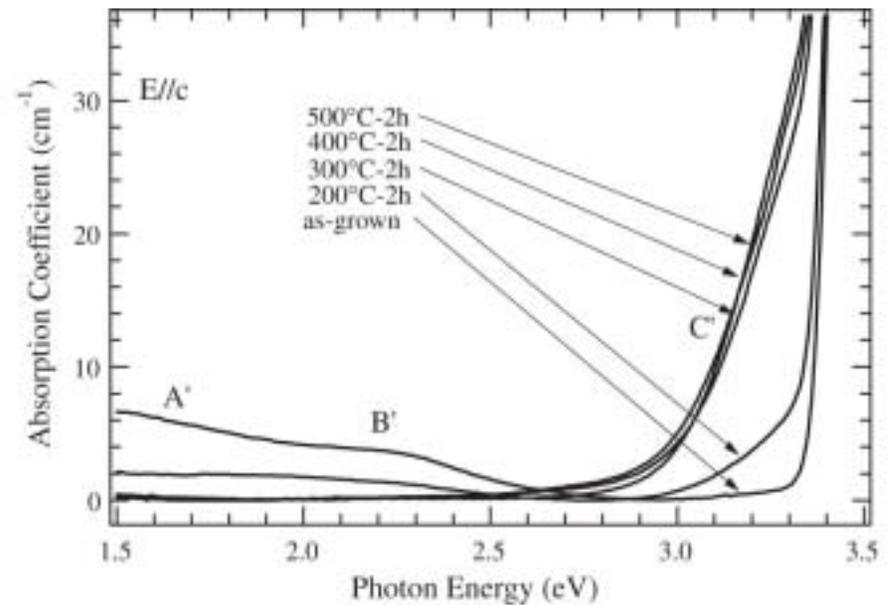
PDOS with the oxygen vacancies concentration in  $\text{TiO}_2$  crystal.



# Optical absorption spectra of oxygen deficient $\text{TiO}_2$ in visible light region



Optical absorption spectra of polycrystalline  $\text{TiO}_2$  with different O vacancy contents. (A) updoped  $\text{TiO}_2$ , (B) 12.5 % oxygen vacancies, (C) 6.2 % oxygen vacancies (D) 3.1% oxygen vacancies.



$\text{TiO}_2$  crystals were heat treated by hydrogen gas.  
T. Sekiya, *J. Phys. Soc. Jpn*, Vol. 73, 703



# Conclusion

- The electronic band structures of nitrogen doped and oxygen deficient  $\text{TiO}_2$  with different levels of doping /vacancies (e.g. 12.5%, 6.2% and 3.1%) were obtained;
- Substitutionally doped nitrogen introduce localized N 2p acceptor states above the top of the valence bands, while oxygen vacancies result in the donor states below the bottom of conduction bands;
- The calculated optical absorption spectra of both cases are in good agreement with experimental data.
- The visible light absorption of the nitrogen doped and the oxygen deficient  $\text{TiO}_2$  are very different; the former mainly absorbs the light from 400 to 500 nm, while the latter mainly absorbs the light above 500 nm.



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